

S9251/S12092 series

**High sensitivity in near infrared range  
( $\lambda=900$  nm)**

These are Si APDs that offer enhanced 900 nm band near-infrared sensitivity. They are suitable for applications such as optical rangefinders.

**Features**

- ➔ High sensitivity in near infrared range ( $\lambda=900$  nm)
- ➔ Stable operation

**Applications**

- ➔ Optical rangefinders
- ➔ FSO (free space optics)

**Structure / Absolute maximum ratings**

Type no.	Dimensional out-line/ Window material*1	Package	Effective*2 photosensitive area size (mm)	Absolute maximum ratings		
				Operating temperature Topr (°C)	Storage temperature Tstg (°C)	Soldering conditions
S12092-02	(1)/K	TO-18	$\phi 0.2$	-20 to +85	-55 to +125	260 °C or less, within 10 s
S12092-05			$\phi 0.5$			
S9251-10	(2)/K	TO-5	$\phi 1.0$			
S9251-15			$\phi 1.5$			

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

\*1: K=borosilicate glass

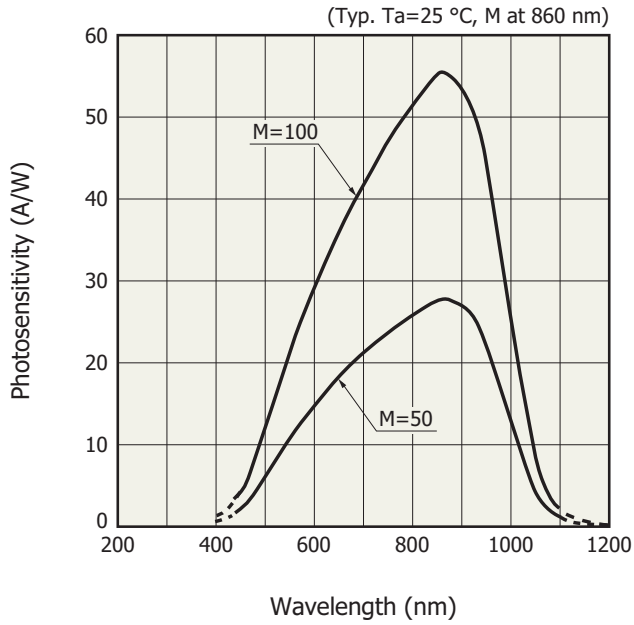
\*2: Area in which a typical gain can be obtained

**Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)**

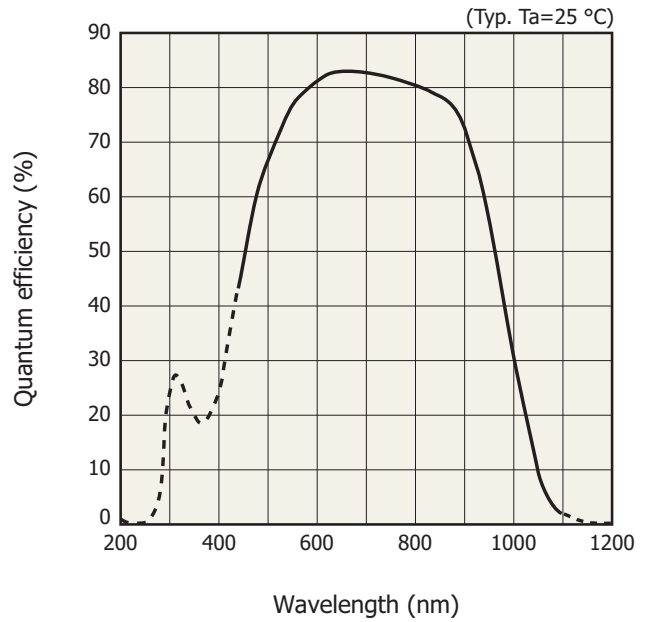
Type no.	Spectral response range $\lambda$ (nm)	Peak*3 sensitivity wavelength $\lambda_p$ (nm)	Photo- sensitivity S M=1 $\lambda=900$ nm (A/W)	Quantum efficiency QE M=1 $\lambda=900$ nm (%)	Breakdown voltage VBR ID=100 $\mu$ A		Temp. coefficient of VBR (V/°C)	Dark*2 current ID		Cutoff*3 frequency fc RL=50 $\Omega$ (MHz)	Terminal*3 capacitance Ct (pF)	Excess*3 noise figure x $\lambda=900$ nm	Gain M $\lambda=900$ nm
					Typ.	Max.		Typ.	Max.				
S12092-02	440 to 1100	860	0.52	72	250	350	1.85	0.1	1	400	0.4	0.3	100
S12092-05								0.2	2		0.7		
S9251-10								0.4	4		1.9		
S9251-15								0.8	8		3.6		

\*3: Values measured at a gain listed in the characteristics table

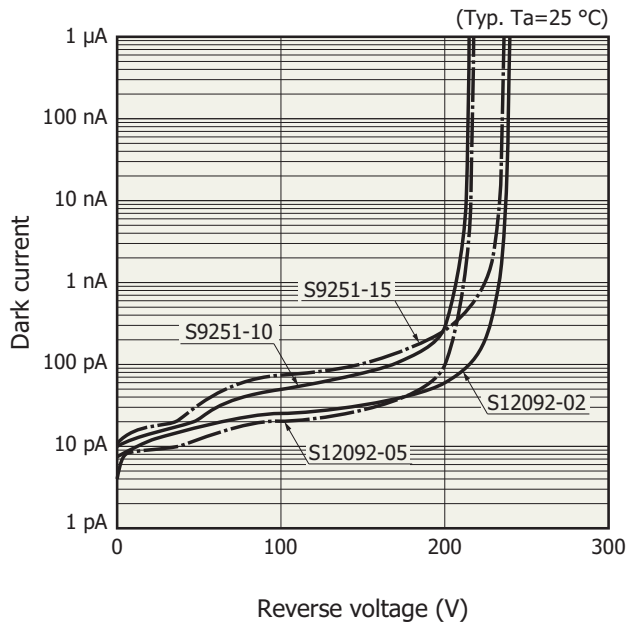
**Spectral response**



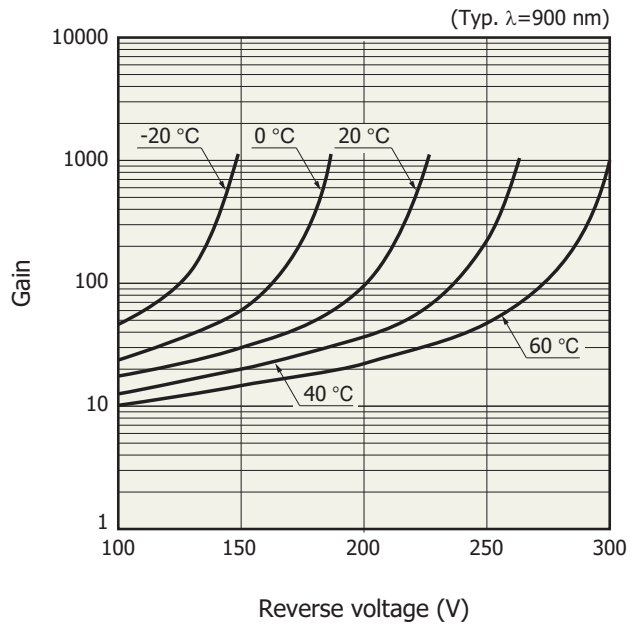
**Quantum efficiency vs. wavelength**



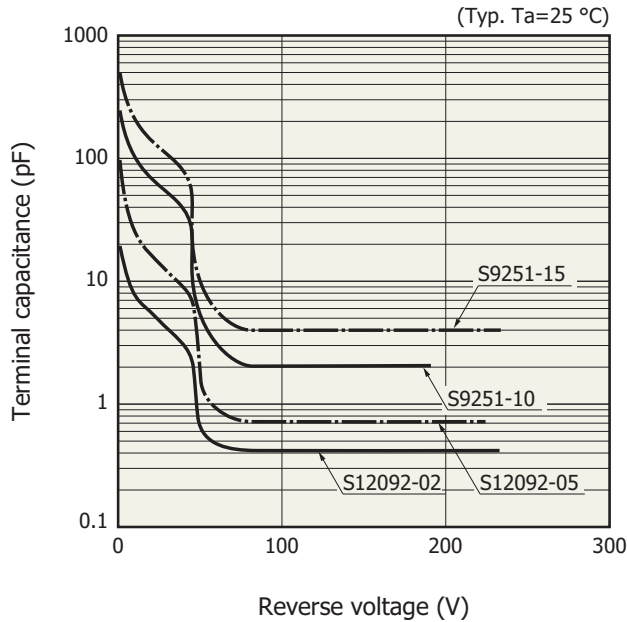
**Dark current vs. reverse voltage**



**Gain vs. reverse voltage**



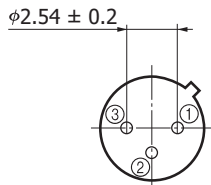
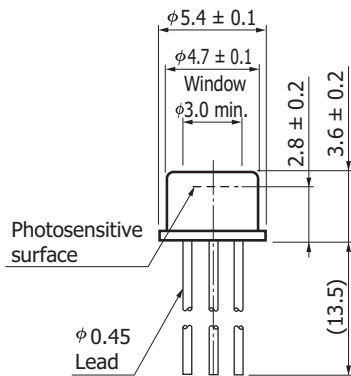
Terminal capacitance vs. reverse voltage



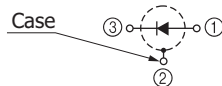
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Dimensional outlines (unit: mm)

(1) S12092-02/-05



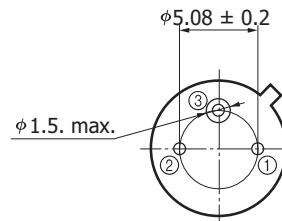
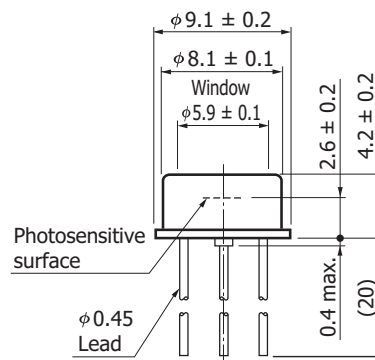
Distance from photosensitive area center to cap center  
 $-0.2 \leq X \leq +0.2$   
 $-0.2 \leq Y \leq +0.2$



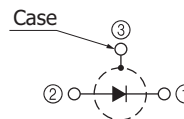
The glass window may extend a maximum of 0.1 mm above the upper surface of the cap.

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(2) S9251-10/-15



Distance from photosensitive area center to cap center  
 $-0.3 \leq X \leq +0.3$   
 $-0.3 \leq Y \leq +0.4$



The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

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## Replacements for previous products

Previous product (listed on the previous datasheet)	Replacement (listed on this datasheet)
S9251-02	S12092-02
S9251-05	S12092-05

\* Products that have been removed from this datasheet

## Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

### Precautions

- Disclaimer
- Metal, ceramic, plastic package products

### Technical information

- Si APD

Information described in this material is current as of March 2017.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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# HAMAMATSU

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